NSN 5962-01-381-9479

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Body	Length:
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Between 0.810 inches and 0.830 inches

Body Width:

Between 0.404 inches and 0.416 inches

Body Height:

0.132 inches

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Programmable and monolithic and w/enable and w/disable and high impedance

Inclosure Material:

Ceramic

Inclosure Configuration:

Flat pack

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

28 input

Current Rating Per Characteristic:

10.00 microamperes reverse current, dc blank

Terminal Surface Treatment:

Solder

Product Name:

Flash eeprom

Voltage Rating And Type Per Characteristic:

-2.0 volts power source and 7.0 volts power source

Capitance Rating Per Characteristic:

10.00 input picofarads and 12.00 output picofarads

Time Rating Per Chacteristic:

250.00 nanoseconds access

Memory Device Type:

Eeprom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

32 flat leads

Shelf Life:

N/a

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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